Diode Semiconductor Device - Page 1 of 1



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Inclosure Mat	#1a1.
Metal	
Overall Lengt	1:
0.180 inches	
Terminal Leng	ith:
1.250 inches	
Mounting Met	hod:
Terminal	
Features Prov	ided:
Hermetically se	aled case
Semiconducto	or Material:
Silicon	
Voltage Ratin	g In Volts Per Characteristic:
1.2 regulator	voltage
Current Ratin	g Per Characteristic:
4.00 amperes	source cutoff current
Power Rating	Per Characteristic:
500.0 milliwatt	s small-signal input power, common-collector preset
Maximum Ope	erating Tempurature Per Measurement Point:
200.0 degrees	celsius ambient air
Terminal Type	And Quantity:
2 uninsulated v	vire lead
Shelf Life:	
N/a	
Unit Of Meası	ire:
Demilitarizatio	on:
No	
Fiig:	
A110a0	